# NSN 5961-00-113-0326

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# **Inclosure Material:**

Metal

**Overall Length:** 

0.260 inches

# **Terminal Length:**

1.500 inches

# **Overall Diameter:**

0.370 inches

### Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-5

**Electrode Internally-electrically Connected To Case:** 

Collector

#### **Mounting Method:**

Terminal **Terminal Circle Diameter:** 

# 0.200 inches

# **Features Provided:**

Hermetically sealed case

#### **Semiconductor Material:**

Silicon

#### Voltage Rating In Volts Per Characteristic:

70.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 200.00 milliamperes source cutoff current and 700.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

5.0 watts small-signal input power, common-collector preset

#### **Maximum Operating Tempurature Per Measurement Point:**

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Shelf Life:

N/a

#### Unit Of Measure:

#### **Demilitarization:**

No

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